A high-performance bi-layered TiO2 nanotube membrane possessing simultaneously large surface areas for dye anchoring, excellent electron transport and strong light scattering is proposed to achieve high power conversion efficiency in dye-sensitized solar cells. The bi-layered TiO2 nanotube arrays with different diameters are fabricated by a versatile and simple electrochemical anodization approach. The large diameter nanotube layer provides strong light-scattering while the small diameter layer provides efficient electron transport and large surface area. When the bi-layered TiO2 nanotube membrane is attached to a conventional TiO2 nanoparticle absorption layer to form a hybrid structured photoanode, a high power conversion efficiency of 6.52% can be achieved.

**Experimental section**

The bi-layered TiO2 nanotubes with different diameters were fabricated by anodization in a conventional two-electrode electrochemical cell. Titanium sheets were used as the working electrode while the counter electrode was Pt foil with the distance between the electrodes being 2 cm. The surface-finished Ti foil was first processed in a used (about 10 h) electrolyte (0.5 wt% NH4F, 10 vol% H2O and 1.5 M lactic acid in ethylene glycol, anodization electrolyte 1) to fabricate the top-layer of large diameter nanotubes. The voltage was fixed at 120 V
for 10 min, and then gradually increased to 180 V for 10 min at a rate of 0.1 V s⁻¹. Then the Ti foil with the large diameter nanotubes on top was further anodized at 60 V in an ethylene glycol electrolyte containing 0.5 wt% NH₄F and 3 vol% H₂O (anodization electrolyte 2) to synthesize the second-layer of small diameter nanotubes with different lengths by changing the anodization time.²⁰,²¹ The as-grown bi-layered nanotubes were annealed at 450 °C for 2 h followed by a further anodization at 60 V to obtain free-standing bi-layered TiO₂ nanotube membranes.²² For comparison, a single layer of small diameter TiO₂ nanotube membrane of the same thickness as the bi-layered one was fabricated by anodizing directly at 60 V in anodization electrolyte 2.

The resulting membranes were annealed at 650 °C for 2 h before they were adhered to the FTO substrate with the TiO₂ NP layer, which was synthesized via a doctor-blade method (two edges of the FTO glass were covered with 3M tape mask to control the thickness of the NP layer, followed by sliding a glass rod along the tape spacer to obtain a uniform TiO₂ NP layer). Then the prepared photoanode was further sintered at 450 °C for 2 h, followed by immersing in a dye-containing solvent (0.3 mM, N719 dye) for 3 days. A hot-melter was used to separate the sensitized electrode and the counter electrode which was prepared by thermal decomposition of H₂PtCl₆ iso-propanol solution on FTO glass at 380 °C for 30 min. The interspace was filled with a liquid electrolyte of DMPII/LiI/I₂/TBP/GuSCN in 3-methoxypropionitrile.

The microstructure and morphology of the TiO₂ nanotubes were characterized by field-emission scanning electron microscopy (FESEM, JEOL JSM-6335F). The current density–voltage (J–V) characteristics were analyzed using a sourcemeter (Model 2420, Keithley) under AM 1.5G illumination (100 mW cm⁻²) provided by a 300 W solar simulator (Model 91160, Newport-Oriel Instruments). Transmittance spectra were acquired using a UV-vis spectrophotometer (Model UV-2550, Shimadzu). To measure the amount of dye loading, we first immersed the sensitized electrode in 0.1 M NaOH aqueous solution for desorption. Then the concentration of desorbed dye was estimated by measuring the dye absorption at 502 nm using UV-vis spectrophotometer. The normalized IPCE values were measured with an IPCE system equipped with a Xenon lamp (Oriel 66902, 300 W), a monochromator (Newport 66902), and a dual channel power meter (Newport 2931_C) equipped with a Si detector (Oriel 76175_71580). Electrochemical impedance spectroscopy (EIS) was performed in the dark at various bias voltages with the CHI 660C electrochemical workstation (CH Instruments). The amplitude of the alternative signal was 10 mV and the frequency ranged from 10⁻¹ to 10⁷ Hz.

**Result and discussion**

The FESEM images of the bi-layered TiO₂ nanotubes with different diameters are shown in Fig. 1, with large diameter nanotubes in the upper layer and small ones underneath. TiO₂ nanotubes with large diameter are normally fabricated by anodizing in an electrolyte with much water content and under a larger applied voltage.²³,²⁴ Here, the used electrolyte added with LA was utilized to prevent too large a current density at high anodization voltages.²⁵-²⁷ The diameters of the top-layer of large diameter nanotubes (LNT) are about 500 nm (viewed from the bottom) with the thickness ~2 μm. The diameter of the second-layer small diameter nanotubes (SNT) is around 120 nm, which were obtained by anodization at 60 V. As seen from the Fig. 1c and d, the thin tube wall at the top of the top-layer LNT becomes thicker at the LNT bottom and the newly formed second-layer SNT was initiated from tube walls of the top-layer.²⁸

We firstly fabricated the DSSC based on SNT and NP layers according to the experimental procedure reported before²² to examine the photovoltaic performance. The photoanodes were constructed of ~5 μm NP with ~15 μm free-standing SNT membranes which were pre-annealed at 450, 650, 750 °C, respectively (denoted as NP5 + SNT15). The XRD patterns of these photoanodes (Fig. S1a†) demonstrate that no rutile phase could be found when annealed at 450 and 650 °C, while a phase transition from anatase to rutile can be observed when annealed at 750 °C. Meanwhile, the average grain size slowly increased from 33 to 41 nm and the prominent anatase peak was narrowed with increasing pre-annealing temperatures from 450 to 750 °C. The photocurrent density–voltage (J–V) characteristics of DSSCs based on these bi-layered photoanodes (NP5 + SNT15) are shown in Fig. S1b and Table S1.† The short-circuit current density (J_sc) increased with increasing pre-annealing temperature from 450 to 650 °C due to the pure anatase phase with improved crystallinity. It decreased at 750 °C due to the appearance of rutile phase. The open-circuit voltage (V_oc) attained a ~70 mV increment when the annealing temperature increased from 450 to 750 °C. As a result of the enhancement in both J_sc and V_oc, the efficiency of the 650 °C-annealed samples reached the maximum of 5.05%. To better illustrate the underlying mechanisms, the electrochemical properties of the DSSCs based on NP5 + SNT15 photoanodes were characterized.
by electrochemical impedance spectroscopy (EIS) measurement in the dark at different applied bias voltages (Fig. S1c and d†). The recombination times of the electrons ($\tau_e$) at TiO$_2$/electrolyte interfaces for the 650 °C- and 750 °C-annealed samples are shorter than the 450 °C-annealed one, owing to the enhanced crystallinity which results in decreased number of traps and faster electron transport. The diameter of the medium-frequency semicircle in the Nyquist plot (Fig. S1d†) increased with increasing pre-annealing temperature, denoting larger recombination resistance ($R_{sc}$) at the TiO$_2$/dye/electrolyte interfaces. Due to the decreased number of traps, lower recombination probability could be achieved. Therefore the SNT pre-annealed at 650 °C with good crystallinity and pure anatase phase shows the best photovoltaic performance of DSSCs.

The large diameter TiO$_2$ nanotubes (LNT) owns effective light scattering, and in the present work, the bi-layered TiO$_2$ nanotubes were successfully fabricated by growing the scattering layer (LNT) on the top of the electron transport layer (SNT). By adhering the bi-layered TiO$_2$ nanotubes onto the NP layer, a three-layered photoanode was successfully fabricated, which has the following advantages: (1) the bottom NP layer provides large surface area and transparency for dye absorption; (2) the middle SNT layer guarantees superior electron transport; and (3) the upper LNT thin layer offers adequate light-scattering capability. The transmittance spectra of the three types of photoanodes on FTO glass are shown in Fig. 2a. The photoanode consisting of only the NP layer (NP15, 15 μm in thickness) shows the highest transmittance. When SNT is attached to the NP layer, the photoanode (NP5 + SNT15) shows decreased transmittance, but is still transparent. Finally, when the 2 μm LNT is used as the scattering layer, the photoanode (NP5 + SNT15 + LNT2) becomes translucent, showing the superior light-scattering property of LNT.

The $J$–$V$ curves and photovoltaic properties of above samples are shown in Fig. 2b and Table 1. In our work, the optimum thickness of the TiO$_2$ NP reference photoanode was about 15 μm (NP15), better than a thicker NP layer of 19 μm (NP19), which is consistent with the previous results (about 12–15 μm) for high efficiency DSSCs. The NP15 cell shows efficiency ($\eta$) of 4.71%, with the $J_{SC}$ of 10.20 mA cm$^{-2}$ and $V_{OC}$ of 0.703 mV. By applying the high temperature pre-annealed SNT to the photoanode, which has the excellent electron transport property, a noticeable improvement is achieved in $V_{OC}$ as well as $J_{SC}$ resulting in an efficiency of 5.05%. The use of the light-scattering LNT layer further improves the efficiency to 5.42%. It should be noted that the use of the LNT also increases the dye loading amount. However, since the LNT is the last layer in the photoanode and the injected electrons take a longer distance (as compared to NP and SNT layers) to reach the FTO electrode, the increase in $J_{SC}$ is not proportional to the increase in dye loading amount. The incident-photon-to-current conversion efficiency (IPCE) spectra are also depicted to further investigate the light-harvesting performance. As shown in Fig. S2, the main enhancement caused by the scattering layer occurs in the long wavelength side, which is the desired wavelength range for light harvesting enhancement in DSSCs.

The effect of thickness of each layer was further studied and several samples, namely, NP5 + SNT15 + LNT2, NP9 + SNT10 + LNT2, NP9 + SNT15 + LNT2, and NP15 + SNT10 + LNT2 (the numbers representing the thickness of each layer), are fabricated. Fig. 3 and Table S2† display the thickness dependence of the $J$–$V$ curves and the photovoltaic performance of these samples. The systematically increased $J_{SC}$ with increased NP

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### Table 1 Photovoltaic properties of the DSSCs with and without the scattering layers

<table>
<thead>
<tr>
<th>Samples</th>
<th>Thickness in each layer (μm)</th>
<th>$J_{SC}$ (mA cm$^{-2}$)</th>
<th>$V_{OC}$ (V)</th>
<th>FF</th>
<th>Relative dye loading</th>
<th>$\eta$ (%)</th>
</tr>
</thead>
<tbody>
<tr>
<td>NP15</td>
<td>15</td>
<td>10.20</td>
<td>0.703</td>
<td>0.657</td>
<td>0.574</td>
<td>4.71</td>
</tr>
<tr>
<td>NP5 + SNT15</td>
<td>5/15</td>
<td>11.07</td>
<td>0.732</td>
<td>0.623</td>
<td>0.419</td>
<td>5.05</td>
</tr>
<tr>
<td>NP5 + SNT15 + LNT2</td>
<td>5/15/2</td>
<td>11.39</td>
<td>0.758</td>
<td>0.627</td>
<td>0.474</td>
<td>5.42</td>
</tr>
<tr>
<td>NP9 + SNT15 + LNT2</td>
<td>9/15/2</td>
<td>13.17</td>
<td>0.760</td>
<td>0.651</td>
<td>0.582</td>
<td>6.52</td>
</tr>
<tr>
<td>NP19</td>
<td>19</td>
<td>7.04</td>
<td>0.700</td>
<td>0.660</td>
<td>0.679</td>
<td>3.25</td>
</tr>
</tbody>
</table>
layer thickness is resulted from the combined effect of more dye-loading due to the NP layer and the superior charge transport due to the SNT layer. The highest efficiency of 6.52% is attained in the device NP9 + SNT15 + LNT2 with the $J_{SC}$ as high as 13.17 mA cm$^{-2}$. Further increasing the thickness of NP to 15 μm (NP15 + SNT10 + LNT2) induced decreased $J_{SC}$ and $\eta$ since the photoanode now is too thick for electron collection.

A further elucidative insight into the electrochemical behavior of the multi-layered DSSCs was also provided by the EIS measurement in the dark at different applied bias voltages. As shown in Fig. 4a, the electron recombination time ($\tau_r$) of NP5 + SNT15 is apparently longer than that of the NP based photoanode. Meanwhile, the diameter of the medium-frequency semicircle in the Nyquist plot (Fig. 4b) of NP5 + SNT15 is also significantly larger than that of NP15, confirming the superior electron transport property of the high temperature annealed SNT and its contribution to the photovoltaic performance. The addition of the light-scattering layer of LNT on top of SNT slightly decreases the $\tau_r$. Since the contribution from the strong light scattering, the efficiency of NP5 + SNT15 + LNT2 is higher than that of NP5 + SNT15.

Conclusions

A novel multi-layered photoanode was designed to achieve simultaneously high dye-loading amount, excellent electron-transport and strong light-scattering for DSSC applications. With a proper thickness of each layer in the photoanode, a PCE as high as 6.52% has been achieved in the NP9 + SNT15 + LNT2 cell, as compared with the PCE of 4.71% in a reference NP15 cell. Our work disclosed the importance of the design of multi-layered photoanode with each layer providing its different functionality in achieving high efficiency DSSCs.

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Notes and references